## **Supplementary Information**

## List of supplementary information

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3 mA, 1000 V	
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 Table S1: The average and fold change of impurities present in tantalum pin upon change in current when normalized against 3 mA, 1000 V

Current (mA)	Si28		P31		Na23		Nb93	
	Average (ppm)	Fold change	Average (ppm)	Fold change	Average (ppm)	Fold change	Average (ppm)	Fold change
0.5	56.4	4.1	5.3	4.1	9.3	0.6	6.4	1.1
1.0	41.9	3.1	3.8	2.9	10.2	0.7	7.2	1.3
1.5	29.3	2.1	2.7	2.1	11.3	0.7	6.9	1.2
2.0	20.8	1.5	2.0	1.5	12.2	0.8	6.3	1.1
2.5	16.3	1.2	1.6	1.2	13.8	0.9	5.9	1.0
3.0	13.7	1.0	1.3	1.0	15.5	1.0	5.7	1.0
3.5	12.4	0.9	1.2	0.9	18.1	1.2	5.8	1.0
4.0	11.2	0.8	1.1	0.8	20.2	1.3	5.8	1.0
4.5	10.2	0.7	1.0	0.7	22.0	1.4	5.6	1.0
5.0	9.3	0.7	0.9	0.7	23.8	1.5	5.5	1.0

Voltage (V)	Si28		P31		Na23		Nb93	
	Average (ppm)	Fold change	Average (ppm)	Fold change	Average (ppm)	Fold change	Average (ppm)	Fold change
600	11.2	0.9	1.1	0.8	13.5	0.9	4.5	0.7
700	10.9	0.9	1.1	0.8	14.7	0.9	4.9	0.8
800	10.9	0.9	1.2	0.8	15.6	1.0	5.4	0.9
900	11.5	0.9	1.3	0.9	15.8	1.0	5.7	1.0
1000	12.2	1.0	1.4	1.0	15.7	1.0	6.0	1.0
1100	13.7	1.1	1.7	1.2	15.7	1.0	6.4	1.1
1200	15.4	1.3	2.0	1.4	15.9	1.0	6.7	1.1
1300	17.3	1.4	2.3	1.6	15.8	1.0	6.9	1.2
1500	23.2	1.9	3.3	2.3	15.9	1.0	7.5	1.2

**Table S2:** The average and fold change of impurities present in tantalum pin upon change in voltage whennormalized against 3 mA, 1000 V